

Low-Jitter Precision CMOS Oscillator

Features

- Low RMS Phase Jitter: <1 ps (typ.)
- High Stability: ±10 ppm, ±20 ppm, ±25 ppm, ±50 ppm
- · Wide Temperature Range:
 - Automotive: -55°C to +125°C
 - Ext. Industrial: -40°C to +105°C
 - Industrial: -40°C to +85°C
 - Commercial: -20°C to +70°C
- · High Supply Noise Rejection: -50 dBc
- · Wide Freq. Range: 2.3 MHz to 170 MHz
- · Small Industry Standard Footprints
 - 2.5 mm x 2.0 mm, 3.2 mm x 2.5 mm, 5.0 mm x 3.2 mm, and 7.0 mm x 5.0 mm
- Excellent Shock and Vibration Immunity
 - Qualified to MIL-STD-883
- · High Reliability
 - 20x Better MTF than Quartz Oscillators
- · Low Current Consumption
- Supply Range of 2.25 to 3.6V
- Standby and Output Enable Function
- · Lead-Free and RoHS Compliant

Applications

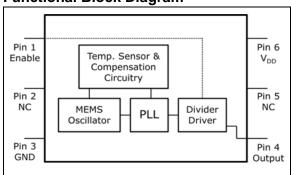
- · Storage Area Networks
 - SATA, SAS, Fibre Channel
- Passive Optical Networks
 - EPON, 10G-EPON, V GPON, 10G-PON
- Ethernet
 - 1G, 10GBASE-T/KR/LR/SR, and FCoE
- · HD/SD/SDI Video and Surveillance
- PCI Express
- · Display Port

General Description

The DSC1101 and DSC1121 series of high performance oscillators utilize a proven silicon MEMS technology to provide excellent jitter and stability over a wide range of supply voltages and temperatures. By eliminating the need for quartz or SAW technology, MEMS oscillators significantly enhance reliability and accelerate product development, while meeting stringent clock performance criteria for a variety of communications, storage, and networking applications.

DSC1101 has a standby feature that allows it to completely power-down when EN pin is pulled low; whereas for DSC1121, only the outputs are disabled when EN is low. Both oscillators are available in industry standard packages, including the small 2.5 mm x 2.0 mm, and are "drop-in" replacements for standard 4-pin CMOS guartz crystal oscillators.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

Note: 1000+ years of data retention on internal memory.

TABLE 1-1: DC CHARACTERISTICS

Electrical Characteristics							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Supply Voltage (Note 1)	V_{DD}	2.25	_	3.6	V	_	
		_	_	0.095		DSC1101, EN pin low, output is disabled	
Supply Current	I _{DD}	_	20	22	mA	DSC1121, EN pin low, output is disabled	
		_	31	35		Output enabled, $C_L = 15 \text{ pF}$, $F_0 = 100 \text{ MHz}$	
Frequency Stability		_	_	±10		Ext Comm. & Ind. only	
(Including frequency variations due to initial	Δ f			±20	nnm	All temp ranges	
tolerance, temp. and	ΔΙ	_		±25	ppm	All temp ranges	
power supply voltage.)		_	_	±50		All temp ranges	
Aging	Δ f	_	_	±5	ppm	1 year @ 25°C	
Startup Time (Note 2)	t _{SU}	_		5	ms	T = 25°C	
Input Logic Levels	V _{IH}	0.75×V _{DD}		_			
Input Logic High Input Logic Low	V _{IL}	_	_	0.1×V _{DD}	V	_	
Output Disable Time (Note 3)	t _{DS}	_	_	5	ns	_	
Output Enghla Time		_		5	ms	DSC1101	
Output Enable Time	t _{EN}	_	_	20	ns	DSC1121	
Enable Pull-up Resistor (Note 4)	_	_	40	_	kΩ	Pull-up Resistor Exist	
CMOS Output							
Output Logic Levels	V _{OH}	0.9×V _{DD}	_	_			
Output Logic High Output Logic Low	V _{OL}	_	_	0.1×V _{DD}	V	I = ±6 mA	

Note 1: Pin 6 V_{DD} should be filtered with 0.1 μF capacitor.

- 2: t_{SU} is time to 100 ppm of output frequency after V_{DD} is applied and outputs are enabled.
- **3:** Output Waveform and Test Circuit figures define the parameters.
- 4: Output is enabled if pad is floated or not connected.

TABLE 1-1: DC CHARACTERISTICS (CONTINUED)

Electrical Characteristics	Electrical Characteristics								
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions			
Output Transition Time	t _R	_	1.1	2		20% to 80%			
Rise Time Fall Time	t _F	_	1.3	2	ns	C _L = 15 pF			
Frequency	£	2.3	_	170	MHz	C_L = 15 pF, -20°C to +70°C and -40°C to +85°C			
	f ₀	3.3	_	170		C_L = 15 pF, -40°C to +105°C and -55°C to +125°C			
Output Duty Cycle	SYM	45	_	55	%	_			
Period Jitter	J _{PER}	_	3	_	ps _{RMS}	F _{OUT} = 125 MHz			
Integrated Phase Noise		_	0.3	_		200 kHz to 20 MHz @ 125 MHz			
	J _{PH}		0.38		ps _{RMS}	100 kHz to 20 MHz @ 125 MHz			
		_	1.7	2		12 kHz to 20 MHz @ 125 MHz			

Note 1: Pin 6 V_{DD} should be filtered with 0.1 μF capacitor.

2: t_{SU} is time to 100 ppm of output frequency after V_{DD} is applied and outputs are enabled.

3: Output Waveform and Test Circuit figures define the parameters.

4: Output is enabled if pad is floated or not connected.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Operating Temperature Range (T)	T _A	-20	_	+70	°C	Ordering Option E
	T _A	-40	_	+85	°C	Ordering Option I
	T _A	-40	_	+105	°C	Ordering Option L
	T _A	-55	_	+125	°C	Ordering Option M
Junction Operating Temperature	T _J	_	_	+150	°C	_
Storage Temperature Range	T _A	-40	_	+150	°C	_
Soldering Temperature Range	T _S	_	_	+260	°C	40 sec. max

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A , T_J , θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 NOMINAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

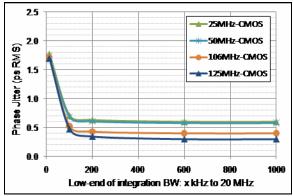


FIGURE 2-1: Phase Jitter (Integrated Phase Noise).

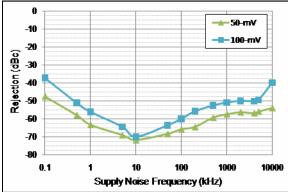


FIGURE 2-2: Power Supply Rejection Ratio.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1. Pin order and descriptions apply across all package types.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number 7x5 w/ Pad	Pin Number 7x5 w/o Pad	Pin Number 5x3.2	Pin Number 3.2x2.5	Pin Number 2x2.5	Pin Name	Description
1	1	1	1	1	EN	Enable.
2	2	2	2	2	NC	Do not connect.
3	3	3	3	3	GND	Ground.
4	4	4	4	4	OUT	Output.
5	5	5	5	5	NC	Do not connect.
6	6	6	6	6	V_{DD}	Supply voltage.
PAD	_	_	_	_	PAD	Tie to ground.

TABLE 3-2: OUTPUT ENABLE MODES

EN Pin	DSC1101	DSC1121
High	Output Active	Output Active
NC	Output Active	Output Active
Low	Standby	Output Disabled

4.0 OUTPUT WAVEFORM

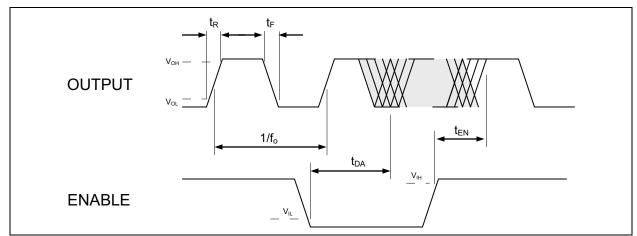


FIGURE 4-1: DSC1101/21 Output Waveform.

5.0 TYPICAL TERMINATION SCHEME

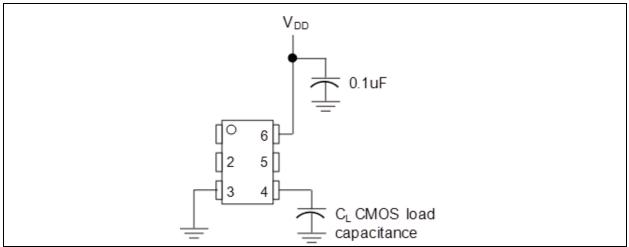


FIGURE 5-1: Typical Termination Scheme for DSC1101/21.

6.0 BOARD LAYOUT (RECOMMENDED)

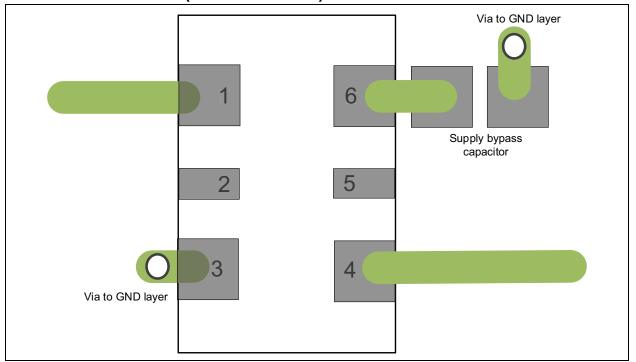
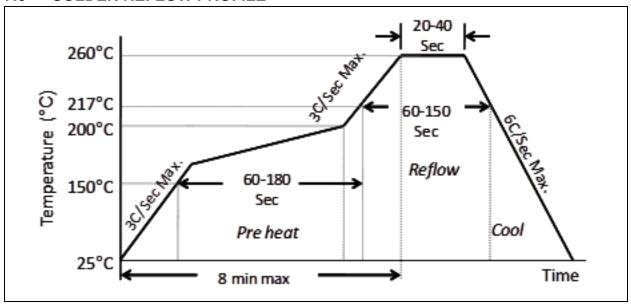


FIGURE 6-1: DSC1101/21 Recommended Board Layout.

7.0 SOLDER REFLOW PROFILE



MSL 1 @ 260°C refer to JSTD-020C					
Ramp-Up Rate (200°C to Peak Temp)	3°C/Sec. Max.				
Preheat Time 150°C to 200°C	60-180 Sec.				
Time Maintained Above 217°C	60-150 Sec.				
Peak Temperature	255-260°C				
Time within 5°C of Actual Peak	20-40 Sec.				
Ramp-Down Rate	6°C/Sec. Max.				
Time 25°C to Peak Temperature	8 minute Max.				

8.0 PACKAGING INFORMATION

8.1 **Package Marking Information**

6-Pin CDFN/VDFN*

XXXXXX **DCPYYWW** 0SSS

Example

0750000 **DCP1723** 0421

Legend: XX...X Product code, customer-specific information, or frequency in MHz

without printed decimal point

Υ Year code (last digit of calendar year) ΥY Year code (last 2 digits of calendar year) WW Week code (week of January 1 is week '01')

SSS

Alphanumeric traceability code
Pb-free JEDEC® designator for Matte Tin (Sn) (e3)

This package is Pb-free. The Pb-free JEDEC designator (@3)) can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle

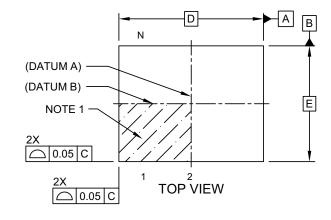
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

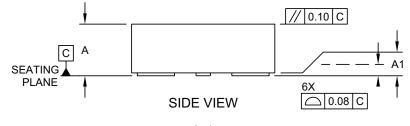
Underbar (_) and/or Overbar (¯) symbol may not be to scale.

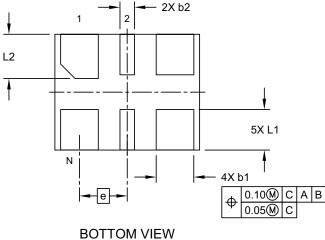
6-Lead VDFN 2.5 mm x 2.0 mm Package Outline and Recommended Land Pattern

6-Lead Very Thin Dual Flatpack No-Leads (J7A) - 2.5x2.0 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



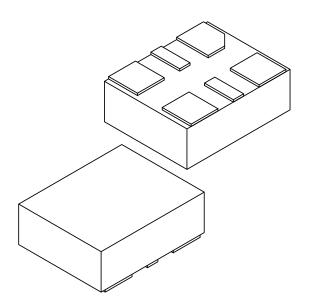




Microchip Technology Drawing C04-1005A Sheet 1 of 2

6-Lead Very Thin Dual Flatpack No-Leads (J7A) - 2.5x2.0 mm Body [VDFN]

lote: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
	Units	IVIILLIIVIL I LING			
Dimer	nsion Limits	MIN	NOM	MAX	
Number of Terminals	N		6		
Pitch	е		0.825 BSC		
Overall Height	Α	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Overall Length	D	2.50 BSC			
Overall Width	E	2.00 BSC			
Terminal Width	b1	0.60	0.65	0.70	
Terminal Width	b2	0.20	0.25	0.30	
Terminal Length	L1	0.60	0.70	0.80	
Terminal Length	L2	0.665	0.765	0.865	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

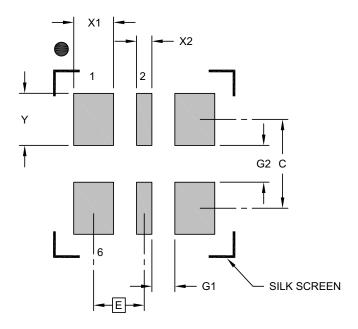
 ${\tt BSC: Basic \ Dimension. \ Theoretically \ exact \ value \ shown \ without \ tolerances.}$

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1005A Sheet 2 of 2

6-Lead Very Thin Dual Flatpack No-Leads (J7A) - 2.5x2.0 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	N	MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	
Contact Pitch	E 0.825 BSC				
Contact Pad Width (X4)	X1			0.65	
Contact Pad Width (X2)	X2			0.25	
Contact Pad Length (X6)	Υ			0.85	
Contact Pad Spacing	С		1.45		
Space Between Contacts (X4)	G1	0.38			
Space Between Contacts (X3)	G2	0.60			

Notes:

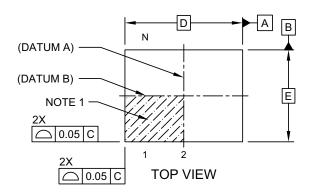
- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

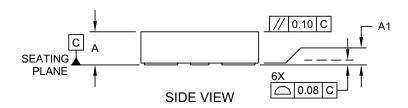
Microchip Technology Drawing C04-3005A

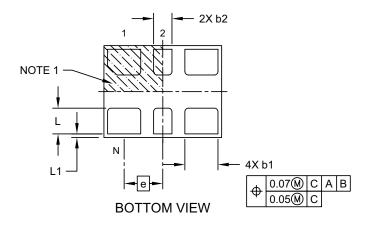
6-Lead VDFN 3.2 mm x 2.5 mm Package Outline and Recommended Land Pattern

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





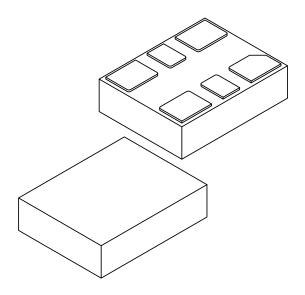


Microchip Technology Drawing C04-1007A Sheet 1 of 2

Note:

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX	
Number of Terminals	N		6		
Pitch	е	1.05 BSC			
Overall Height	Α	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Overall Length	D	3.20 BSC			
Overall Width	E	2.50 BSC			
Terminal Width	b1	0.85	0.90	0.95	
Terminal Width	b2	0.45	0.50	0.55	
Terminal Length	L	0.65	0.70	0.75	
Terminal Pullback	L1		0.10 REF		

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

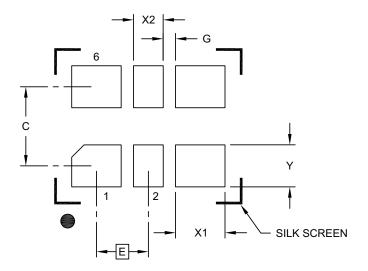
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1007A Sheet 2 of 2

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

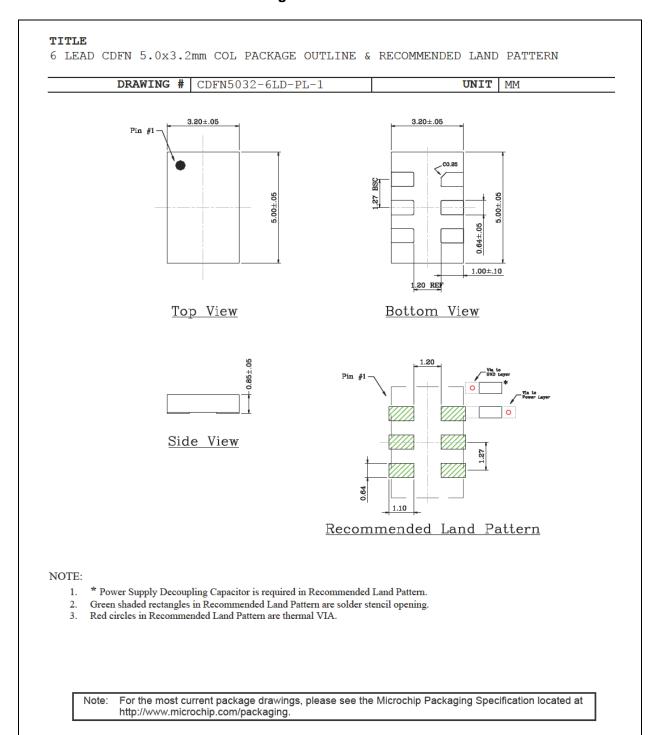
	N	IILLIMETER	S	
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	1.05 BSC		
Contact Pad Spacing	С		1.60	
Contact Pad Width (X4)	X1			1.00
Contact Pad Width (X2)	X2			0.60
Contact Pad Length (X6)	Υ			0.85
Space Between Contacts (X4)	G1	0.25		

Notes:

Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3007A

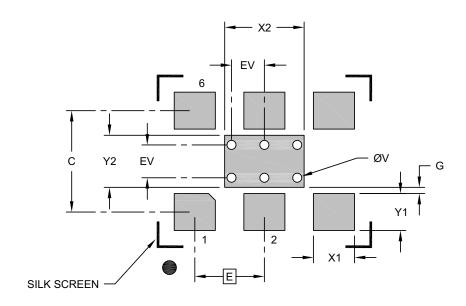
6-Lead CDFN 5.0 mm x 3.2 mm Package Outline and Recommended Land Pattern



6-Lead VDFN 7.0 mm x 5.0 mm Package Outline and Recommended Land Pattern

6-Lead Very Thin Plastic Quad Flat, No Lead Package (H8A) - 7x5 mm Body [VDFN] With 2.8x1.8 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е	2.54 BSC		
Optional Center Pad Width	X2			2.90
Optional Center Pad Length	Y2			1.90
Contact Pad Spacing	C		3.70	
Contact Pad Width (X6)	X1			1.50
Contact Pad Length (X6)	Y1			1.35
Contact Pad to Center Pad (X2)	G	0.20		
Thermal Via Diameter (X6)	V		0.33	
Thermal Via Pitch	EV		1.20	

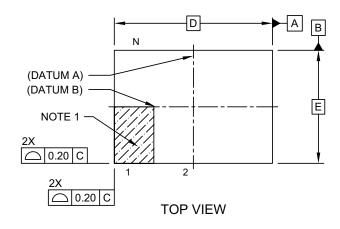
Notes:

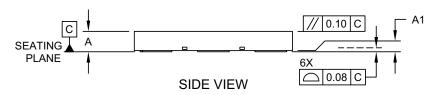
- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

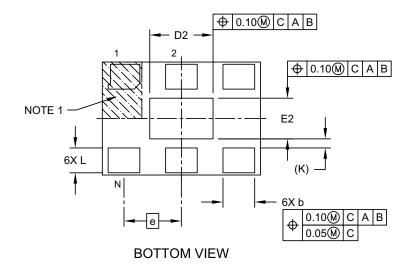
Microchip Technology Drawing C04-3010A

6-Lead Very Thin Plastic Quad Flat, No Lead Package (H8A) - 7x5 mm Body [VDFN] With 2.8x1.8 mm Exposed Pad

ote: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



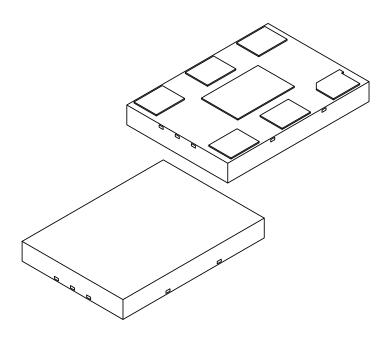




Microchip Technology Drawing C04-1010A Sheet 1 of 2

6-Lead Very Thin Plastic Quad Flat, No Lead Package (H8A) - 7x5 mm Body [VDFN] With 2.8x1.8 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX	
Number of Terminals	N		6		
Pitch	е		2.54	·	
Overall Height	Α	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Overall Length	D	7.00 BSC			
Exposed Pad Length	D2	2.70	2.80	2.90	
Overall Width	E	5.00 BSC			
Exposed Pad Width	E2	1.70	1.80	1.90	
Terminal Width	b	1.35	1.40	1.45	
Terminal Length	Ĺ	1.00	1.10	1.20	
Terminal-to-Exposed-Pad	K		0.20 REF		

Notes:

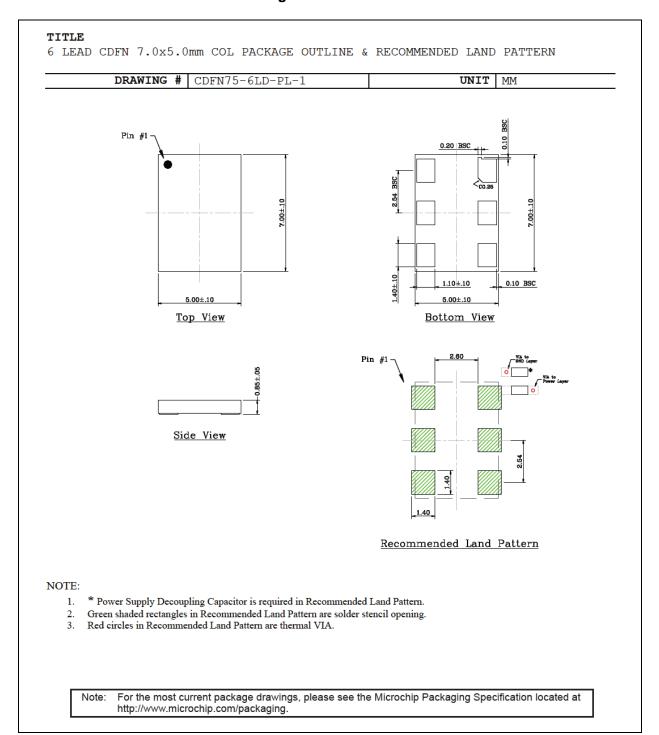
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M $\,$

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1010A Sheet 2 of 2

6-Lead CDFN 7.0 mm x 5.0 mm Package Outline and Recommended Land Pattern



	C	C1	1	Λ	1	/2	1
ப	J	C I		U			ı

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (August 2017)

- Initial creation of document DSC1101/21 to Microchip data sheet template DS20005613A.
- · Minor text changes throughout.

Revision B (December 2017)

- Military temperature range changed to Automotive in Features and Product Identification System.
- Supply Current values updated in Table 1-1.
- Test Circuit section removed.
- Updated Figure 6-1, Recommended Board Layout.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	<u>X</u>	<u>X X -XXX.XXXX X</u>	Ex	Examples:	
Device	Package Ter	mperature Stability Frequency Packag Range Optio		DSC1101AM1-010.0000T: Lov CN Sta	
Device:	DSC1101:	Low-Power Precision CMOS Oscillator with Standby Low-Power Precision CMOS Oscillator		VD per 10	
Package:	A =	6-Lead 7.0 mm x 5.0 mm VDFN	b)	que DSC1101BL2-030.0000:	
Раскаде :	B = C = D = N =	6-Lead 7.0 mm x 3.0 mm VDFN 6-Lead 5.0 mm x 3.2 mm CDFN 6-Lead 3.2 mm x 2.5 mm VDFN 6-Lead 2.5 mm x 2.0 mm VDFN 6-Lead 7.0 mm x 5.0 mm CDFN (no center pa	d)	Lo Cl St Cl tri	
Temperature Range:	E = I = L = M =	-20°C to +70°C (Extended Commercial) -40°C to +85°C (Industrial) -40°C to +105°C (Extended Industrial) -55°C to +125°C (Automotive)	c)	±2 Fi DSC1101DE5-150.0000: Lov CM	
Stability:	1 = 2 = 3 = 5 =	±50 ppm ±25 ppm ±20 ppm ±10 ppm		Sta VD cia ±10 Fre	
Frequency:	XXX.XXXX	= 2.3 MHz to 170 MHz (user-defined)	d)	DSC1101AI2-075.0000T:	
Packing Option:	 T =	110/Tube 1,000/Reel		CI St VI tu 75 qu	

Examples:

w-Power Precision MOS Oscillator with tandby, 6-LD 7.0X5.0 DFN, Automotive Temerature Range, ±50 ppm, 0 MHz Output Freuency, 1,000/Reel

_ow-Power Precision CMOS Oscillator with Standby, 6-LD 5.0X3.2 CDFN, Extended Indusrial Temperature Range, £25 ppm, 30 MHz Output requency, 110/Tube

w-Power Precision MOS Oscillator with tandby, 6-LD 2.5X2.0 DFN, Extended Commeral Temperature Range, 10 ppm, 150 MHz Output requency, 110/Tube

_ow-Power Precision CMOS Oscillator with Standby, 6-LD 7.0X5.0 /DFN, Industrial Temperaure Range, ±25 ppm, 75 MHz Output Frequency, 1,000/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, AnyRate, AVR, AVR logo, AVR Freaks, BeaconThings, BitCloud, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, Heldo, JukeBlox, KEELOQ, KEELOQ logo, Kleer, LANCheck, LINK MD, maXStylus, maXTouch, MediaLB, megaAVR, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, Prochip Designer, QTouch, RightTouch, SAM-BA, SpyNIC, SST, SST Logo, SuperFlash, tinyAVR, UNI/O, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

ClockWorks, The Embedded Control Solutions Company, EtherSynch, Hyper Speed Control, HyperLight Load, IntelliMOS, mTouch, Precision Edge, and Quiet-Wire are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BodyCom, chipKIT, chipKIT logo, CodeGuard, CryptoAuthentication, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet logo, Mindi, MiWi, motorBench, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PureSilicon, QMatrix, RightTouch logo, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2017, Microchip Technology Incorporated, All Rights Reserved. ISBN: 978-1-5224-2480-2



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200

Fax: 480-792-7277 Technical Support:

http://www.microchip.com/ support

Web Address:

www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI

Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis

Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800

Raleigh, NC Tel: 919-844-7510

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110 Tel: 408-436-4270

Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078

ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

China - Beijing Tel: 86-10-8569-7000

China - Chengdu Tel: 86-28-8665-5511

China - Chongqing Tel: 86-23-8980-9588

China - Dongguan Tel: 86-769-8702-9880

China - Guangzhou Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

China - Nanjing Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai Tel: 86-21-3326-8000

China - Shenyang

Tel: 86-24-2334-2829 China - Shenzhen

Tel: 86-755-8864-2200

China - Suzhou Tel: 86-186-6233-1526

China - Wuhan Tel: 86-27-5980-5300

China - Xian Tel: 86-29-8833-7252

China - Xiamen
Tel: 86-592-2388138

China - Zhuhai Tel: 86-756-3210040

ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631

India - Pune Tel: 91-20-4121-0141

Japan - Osaka Tel: 81-6-6152-7160

Japan - Tokyo

Tel: 81-3-6880- 3770

Korea - Daegu Tel: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila Tel: 63-2-634-9065

Singapore Tel: 65-6334-8870

Taiwan - Hsin Chu Tel: 886-3-577-8366

Taiwan - Kaohsiung Tel: 886-7-213-7830

Taiwan - Taipei Tel: 886-2-2508-8600

Thailand - Bangkok Tel: 66-2-694-1351

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

Finland - Espoo Tel: 358-9-4520-820

France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Garching Tel: 49-8931-9700

Germany - Haan Tel: 49-2129-3766400

Germany - Heilbronn Tel: 49-7131-67-3636

Germany - Karlsruhe Tel: 49-721-625370

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Rosenheim Tel: 49-8031-354-560

Israel - Ra'anana Tel: 972-9-744-7705

Italy - Milan Tel: 39-0331-742611

Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Padova Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Norway - Trondheim Tel: 47-7289-7561

Poland - Warsaw Tel: 48-22-3325737

Romania - Bucharest Tel: 40-21-407-87-50

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820